Genetic Map of Bacteriophage $\phi X174$

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Bacteriophage ϕ X174 temperature-sensitive and nonsense mutations in eight cistrons were mapped by using two-, three-, and four-factor genetic crosses. The genetic map is circular with a total length of 24×10^{-4} wt recombinants per progeny phage. The cistron order is D-E-F-G-H-A-B-C. High negative interference is seen, consistent with a small closed circular deoxyribonucleic acid molecule as a genome.

Bacteriophage $\phi X174$ is the smallest virus known to undergo genetic recombination (14, 15). Observed recombination frequencies range from 10^{-6} to 2×10^{-3} wt recombinants per progeny phage (C. A. Hutchison III, Ph.D. Thesis, California Institute of Technology, Pasadena, 1969). In spite of these low recombination frequencies, genetic analysis similar to that performed with bacteriophages T4 (17) and λ (17) has been shown to be possible for $\phi X174$ (C. A. Hutchison III, Ph.D. Thesis) and for the related bacteriophage S13 (1, 18).

To construct a detailed genetic map of $\phi X174$, we examined the results of genetic crosses involving over 100 single-base transition mutants. In this paper, 36 different conditional-lethal mutants in eight cistrons are mapped by using two-, three-, and four-factor genetic crosses. High negative interference (9) is seen, consistent with a constraint for double exchanges imposed by the small circular genome.

A subsequent paper (Benbow et al., in preparation) will show that the combined molecular weights of the $\phi X174$ specific proteins coded by these eight cistrons require over 90% of the genome coding capacity. A correspondence exists between cistron size on the genetic map and protein size determined by sodium dodecyl sulfate polyacrylamide gel electrophoresis. Taken together, these papers show that the genetic map of bacteriophage $\phi X174$ is circular with cistron order and direction of translation D-E-F-G-H-A-B-C.

MATERIALS AND METHODS

KC broth. KC broth (16) was composed of 10 g of tryptone (Difco) and 5 g of KCl, made to 1 liter with distilled water. It was autoclaved for 20 min, and 0.5 ml of 1 M CaCl₂ was added after cooling.

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Denhardt starvation buffer. This buffer (4) was composed of 5 g of KCl, 1 g of NaCl, 1.2 g of tris-(hydroxymethyl)aminomethane (Tris), and 0.1 g of MgSO₄, made to 1 liter with distilled water. The pH was adjusted to 8.1 with HCl, the buffer was autoclaved, and 1.0 ml of 1 M CaCl₂ was added after cooling.

Bottom agar. Bottom agar (16) consisted of 2.5 g of NaCl, 2.5 g of KCl, 10.0 g of agar (Difco), and 10 g of tryptone (Difco), made to 1 liter with distilled water. After autoclaving, 1 ml of 1 M CaCl₂ was added to each liter of medium. Twenty-milliliter plates were poured.

Top agar. Top agar (16) consisted of 5 g of NaCl, 8 g of agar (Difco), and 10.0 g of tryptone (Difco), made to 1 liter with distilled water. The mixture was autoclaved for 15 min to dissolve the agar, bottled, and then autoclaved again.

φX174 nonsense mutants. amN1, amH81, and amH57 were gifts from M. Hayashi. am80, am86, am87, am88, am89, am90, och1, och5, och6, och8, and och11 were isolated in this laboratory by F. Funk (7). cs70 is the cold-sensitive φX174 mutant of Dowell (5). All other stocks were grown from single plaques of the original stocks of Hutchison (Ph.D. Thesis). A list of the conditional-lethal mutants used in this study is given in Table 1.

 ϕ X174 double mutants. $am3ts\gamma$, am3ts79, am3ts9, am3ts4, and am3cs70 were described by Hutchison (Ph.D. Thesis). All other double mutants were isolated from two-factor crosses in which both parental stocks were ultraviolet-irradiated to roughly three lethal "hits" per phage before mating. Screening for double mutants was performed by layering infected, permissive cells in top agar over a prepoured plate containing nonpermissive cells. The plates were incubated at 30 C for 3 hr and then shifted to 40 C for 6 hr. Four plaque types were seen: large-clear, large-turbid, small-clear, and small-turbid. Single plaques of the last type (am-ts double mutants) were tested for inability to grow on C (nonpermissive) at 30 C and on HF4714 (permissive) at 40 C; then single plaque isolates were grown to a high titer.

To test the composition of each double mutant, isolates were back-crossed against each of the two parental mutants. If less than 5×10^{-6} wt recombi-

TABLE 1. Classification of ϕX mutants

Cistron	Mutant
Α	am8, am18, am30, am33, am35, am50, am86, ts128
В	am14, am16, och5, ts9, ts116, och1, och8, och11
C	och6
D	am10, amH81
E	am3, am6, am27
F	am87, am88, am89, amH57, op6, op9, tsh6, ts41D
G	am9, am32, $ts\gamma$, $ts79$
H	amN1, am23, am80, am90, ts4, cs70 ^a

^a cs70 cannot be assigned to a cistron on the basis of complementation tests (5). We anticipate that it will be found in cistron H, based on its segregation during three- and four-factor crosses and on its physiological characteristics.

nants per total number of progeny phage were found, the single and double mutants were assumed to contain the same mutation. To guard against multiple mutants, only double mutants whose individual markers reverted to wild type at a frequency of 10^{-6} to 10^{-7} were used. Complementation tests to verify cistron assignments were carried out by A. J. Shafer. All stocks used had titers above $5 \times 10^9/\text{ml}$ and reversion frequencies below 5×10^{-6} wt per mutant phage.

Bacterial strains. C is the standard nonpermissive host for $\phi X174$ (16).

HF4704 is a nonpermissive thy^- host for $\phi X174$ (11). It is more stringently nonpermissive than C for the *och* mutants used in this study.

HF4714 is permissive for am (UÅG) but not och (UAA) or op (UGA) ϕ X174 nonsense mutants. HF4714 was isolated in this laboratory by Paul Howard-Flanders. All plating efficiencies are defined relative to ϕ X174wt on HF4714 at 37 C.

 $Su2_{am}$ (7) is an alternative *am* suppressor strain for *am80* and *am90*, which will not plate on HF4714. Its plating efficiency relative to HF4714 at 37 C is 0.66 for $wt \phi X174$.

Su2_{och} (7) is an am and an och suppressor strain. Its plating efficiency is 0.66 for $wt \phi X174$.

CIT103 (C. A. Hutchison III, Ph.D. Thesis) is an op suppressor strain with a plating efficiency of 1.00 for $wt \phi X174$.

RMB101 is an am-op double suppressor strain. It was constructed by lysogenizing CIT103 with ϕ 80p Su_{III}⁺ (donated by J. Parkinson). Its plating efficiency for am mutants is generally 1.00 relative to HF4714.

Growth of stocks. Single plaques grown at 30 C for 4 to 5 hr were transferred with a sterile pipette to a culture of permissive cells at $10^8/\text{ml}$ in KC broth. These were gently aerated at 32 C for 2 to 3 hr until the cultures cleared. The lysate was made 0.005 M ethylenediaminetetraacetic acid (EDTA), 0.4 M NaCl, and 6% (w/v) polyethylene glycol 6000. After precipitation in the cold for 1 to 2 hr, lysates were centrifuged at $5,900 \times g$ for 20 min. The pellet (or interface, often not visible) was resuspended in 0.05 M

sodium tetraborate and centrifuged to remove debris. We thank L. Dumas for suggesting the use of polyethylene glycol 6000.

Very-high-titer stocks of cistron E mutants (except am6) were prepared by infecting log-phase HF4704 (nonpermissive) at a multiplicity of infection of 2 and incubating at 32 C for 1.5 hr. Cells were pelleted and artificially lysed with 0.2 mg of lysozyme per ml (in 0.05 m Tris, 0.005 m EDTA, pH 8.1) followed by freezing and thawing three times; the phage were collected as above.

High-titer stocks of mutants in other cistrons were obtained by infecting log-phase cultures of permissive cells at a multiplicity of infection of 2. After 20 min, enough 60% sucrose was added to give a final concentration of 12% sucrose (to delay lysis). After 60 min, phage were collected by polyethylene glycol precipitation as above.

Two-factor genetic crosses (between nonsense mutants). HF4714 (a permissive host for am mutations) was grown to 108 cells/ml at 37 C with gentle aeration. The culture was made 0.003 M KCN and aerated for 10 min. Two 0.5-ml samples of 2×10^8 φX174 mutant phage per ml in KC broth-0.003 м KCN were mixed in a mating tube in an ice bath. A 0.2-ml amount of the KCN-treated bacterial culture was added to each mating tube and incubated at 37 C for 15 min. A 0.2-ml amount of each of the resulting phage-cell complexes was diluted into 20 ml of KC broth. These were vigorously aerated at 36 C for 90 min. Cultures were shaken with chloroform and titered, usually on C and on HF4714 at 37 C. The recombination frequency between am mutants was defined as the titer on C at 37 C divided by the titer on HF4714 at 37 C. Control experiments with a 1:1 mixture of parental phage showed that recombination on a plate was always below a frequency of 5×10^{-6} wt per total progeny phage as was the recombination frequency of a mutant with itself (selfing).

Titers on $Su2_{och}$ were corrected to give HF4714 equivalent titers. Crosses were always performed in HF4714, even when op or och mutants were used. The titer on RMB101 (an am op double suppressor) at 37 C was used directly for $am \times op$ crosses in which the am mutants plated with equal efficiency on RMB101 and HF4714.

Three- and four-factor genetic crosses. A procedure similar to that for two-factor crosses was employed except that growth was at 32 C. Titers were obtained at both 30 and 40 C (37 and 25 C for cs70). To confirm that plating at two temperatures is adequate to determine whether $am \times am$ recombinant progeny from amA $tsC \times amB$ crosses are predominantly wt or ts, a large number of single plaques were grown at 30 C and tested for ability to form plaques at 40 C. The fraction able to do so was similar to that determined from a mass plating at the two temperatures. An analogous control for segregation of the am marker in tsD $amF \times tsE$ crosses was carried out.

Recombination frequencies are defined as follows: for $am\ ts \times am$, as the titer on C at 30 C divided by the titer on HF4714 at 30 C (i.e., ts + wt/total); for $am\ ts \times ts$, as the titer on HF4714 at 40 C divided by the titer on HF4714 at 30 C ($am\ + wt/\text{total}$); for

am $ts \times och$, as the titer on HF4704 at 30 C divided by the corrected titer on Su2_{och} at 30 C (ts + wt/total); for am $ts \times op$, as the titer on C at 30 C divided by the titer on RMB101 at 30 C (ts + wt/total); and for och am \times och, as the titer on HF4714 at 30 C divided by the corrected titer on Su2_{och} at 30 C (am + wt/total). These are equivalent in all tested cases to the two-factor recombination frequencies.

Counting statistics. For each determination of a recombination frequency in Table 2, three plates were counted to measure wt recombinants and three were counted for total progeny. Only crosses with burst sizes in excess of 75 under permissive conditions were tabulated. In Table 2, the numbers in parentheses represent the number of independent determinations used to calculate the average recombination frequency. The genetic map in Fig. 1 represents these two-factor crosses and similar unpublished data in a schematic form. No claim is made that this map represents accurately the linear distance between these mutations.

RESULTS

Two-factor crosses. The average frequency of wild-type recombinants produced in pairwise crosses between $\phi X174$ nonsense mutants is shown in Table 2. Several points may be emphasized.

- (i) Recombination frequencies between closely linked markers often are roughly additive.
- (ii) Recombination frequencies may be ordered to form a circular genetic map, i.e., any marker selected will lie at both ends of a linear map.
- (iii) The length of the complete genetic map is $24.4 \pm 3 \times 10^{-4}$ recombination units as calculated by summing the distances between 6(E) 88(F) 9(G) NI(H) 86(A) 16(B) och6(C)-10(D)-6(E). Map contraction is often seen between distant markers.
- (iv) am3 shows lower recombination frequencies when crossed with certain mutants, such as am23, am88, and op6, than expected from map distances determined with mutants in other cistrons. Most other cistron E mutants (am20, am24, am26, am27, am29, and am34) also show this phenomenon (Benbow, Davis, and Sinsheimer, in preparation).
- (v) Some cistron A mutants, am33 for example, show much higher intracistronic recombination frequencies than anticipated and occasionally higher intercistronic frequencies. Many other cistron A mutants (am8, am30, am81, am83, and am85) also behave in this manner. This phenomenon will be discussed briefly here and in more detail at a later date (Benbow, Davis, and Sinsheimer, in preparation).
- (vi) Some mutants, am23(H) and och6(C) for example, show consistently low recombination frequencies. We believe these represent site-specific recombination effects (Norkin, sub-

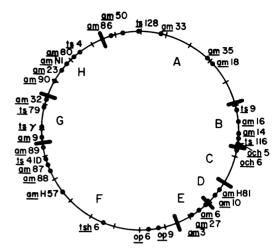


Fig. 1. Frequency of wt recombinants in two-factor genetic crosses between $\phi X174$ conditional lethal mutants is represented schematically. One map unit represents 10^{-4} wt recombinants per total progeny phage, except in the region of cistron A for the reasons noted in the text. Cistron boundaries are arbitrarily drawn. The recombination data for am87, am89, am32, am80, am90, och5, amH81, amH57, am27, and op9 are found in Benbow et al. (in preparation). The order of ts mutations within a cistron relative to the am mutations in the same cistron was determined from three factor crosses (Table 3) and from ts \times ts or ts \times am two-factor crosses (unpublished data).

mitted Ph.D. Thesis, Columbia Univ., New York).

Three- and four-factor crosses. The rationale for three-factor crosses is described in Baker and Tessman (1). Briefly, the progeny of a cross of the type amA $tsC \times amB$ is plated on a nonpermissive (for am mutations) strain at a permissive (for ts mutations) temperature (30 C). The am \times am recombinants are then tested at 30 and 40 C to follow segregation of the ts marker. If amA and amB are closely linked and tsC is a more distant external marker, then when the progeny are predominantly ts the order deduced is amAamB-tsC. If the progeny are predominantly wt, the order deduced is tsC-amA-amB. amA and amB are considered adjacent if they lie in the same cistron or very closely linked cistrons while the ts marker is in a more remote cistron. In most cases, the same result is obtained by plating the progeny from the cross directly at 30 and 40 C on a nonpermissive strain. Analogous reasoning holds for crosses of the type tsD $amE \times tsF$.

An unambiguous order for cistrons A, B, E, F, G, and H is established by the data in Table 3. For essential placements, the reciprocal cross is included since wild-type recombinants occasionally outgrow a predominant mutant geno-

TABLE 2. Two-factor recombination frequencies^a

	(A)	am33 (A)	am35 (A)	<i>am</i> 50 (A)	am86 (A)	am14 (B)	B am16 (B)	ပ <i>ရဗု</i> ပ္ပ	д дт10 (D)	am3 (E)	E am6 (E)	am88 (F)	F 026 (F)	G) am6	am23 (H)	H amN1 (H)
A am18(A)																
am33(A)	±3.2															
am35(A)	+0.1 +0.1	21.2 ± 2.4^{b}														
am50(A)	7.9 ±0.5 ^h	4.5 ±0.6 ^b	13.9 ±1.0 ^b													
am86(A)	11.7 ±2.4 ^h	5.5 ±2.0 (2) ^b	16.8 ±1.5 ^h	0.5 ±0.1 (2)												
а																
<i>am</i> 14(B)	2.8 ±0.3	$\pm 0.4^{b}$	2.8 ±0.3	2.6 ±0.5	4.0 ±0.2											
<i>am</i> 16(B)	2.0 ±0.1	9.1 ±2.8 ^b	2.7 ±0.1	(2) 6.4 ±0.3	7.3 ±1.2	1.3 ±0.3										
ن د	,	,	1	,		•	-									
och6(C)	$\pm 0.2^c$	3.9 ±0.4°	0.7 ±0.1°	4.2 ±1.3°	±0.1℃	1.0 ±0.2	1.3 ±0.3									
D (D)	4	6.2	2.0	0.4	2 4	8	2.3	2.0								
	±0.5	±1:0	±0.5	±0.6	±0.2	±0.2 (2)	±0.4	±0.2								
E am3(E)	4.1	10.8	4,	10.2	8.3	3.4	4.6	1.3	1.5							
	0.0∓	#0.8	±1.0	±1.6	6.0∓	±0.5	6.0∓	±0.1	±0.2							
am6(E)	(5) 6 .6	(3)	(3) 6 .3	(£) 8,3	(5) 6.5	(4) 2.4	(5) 3.5	(5) 0.2	(3) 0.2	0.2						
	±1.0	#0.8	±1.2	±2.0	±2.0	±0.7	±0.4	±0.7°	±0.4	±0.4 (6)						

, am88(F)	10.8	12.4	11.9	8.0	5.3	10.3	9.3	=	14.4	4.	7.1				
	±1.2	±2.1	±0.3	#1.0	6.0±	±0.7	±3.2	±2.2	9.0∓	±0.8	±0.7	*			
op6(F)	6.5	Low	6.0	4.2	1.3	8.4		Low	2.2	1.2		Low			
	±0.2	burst	±0.2	±1.5°	±0.6°	±0.4		burst	±0.1	±0.1		burst			
; am9(G)	.s.	11.5	8.0	8.2	8.9	2.9	4.5	1.2	5.9	8.9	4.7	1.3	Low		
	±1.4	#0.8	±1.0	∓0.8	±0.4	6.0±	±1.2	±0.1°	±2.1	±0.8 (9)	±1.0	±0.2	burst		
_												2000	•		
am23(H)	1.7	2.0	4.7	1.2	0.4	8.1	2.1	Low	5.6	2.2	3.4	3.4		2.1	
	±0.8	±0.4°	±0.5°	±0.1	±0.1°	±0.5	±0.4	burst	±0.3°	0.6	±0.9€	±0.4	+1.4	±0.3°	
<i>am</i> N1(H)	3.0	7.5	3.1	2.0	2.1	(3)° 3.0	(<u>7</u>) 8.7 8.8	4.1	4.6	8. T.	6.2	4.1	8.1	3.1	0.26
	±0.3	±1.2	±0.2	±0.3	±0.3	±0.5	±0.5	±0.2	±0.3	±1.3	€.0±	≠0.6		#0.8	±0.3
				(5)	(5)				(5)	(3)	(5)			<u>(5</u>	(2)
					_										-

Results expressed × 10⁴.
 These cistron A recombination frequencies were used in the construction of Fig. 2 only. Numbers in parentheses represent the number of independent determinations used to calculate the average recombination frequency.
 Exact correspondence between map distance in Fig. 1 or 2 and recombination frequency is not obtained for the reason noted in the text.

Table 3. Three-factor recombination frequencies

		TABLE	. The contact in	
	Recombination	Per cent	Predominant	Order deduced or confirmed
SSO	frequency ^a	1m	genotype	H G F E D C B A H G
(1) amN1 $ts_{\gamma} \times ts79$		33	am	- 1
(2) $amN11s79 \times ts\gamma$	0.8 ± 0.3	8	W	$NI-79-\gamma$
(3) $am88ts\gamma \times ts79$	\mathbb{H}	76	W	7
_	#	96	wt	4-7988
(5) am88ts79 \times op6	H	91	wt	
_	4 #	38	ts	23-664
(7) $am3ts79 \times ts_{\gamma}$	7	25	am	793
(8) $am3ts\gamma \times ts79$		88	wt	7
(9) $am881s79 \times am3$	# 0	66	wt	79883
(10) $am3ts\gamma \times am88$	4.3 ± 0.5	46	ts	7~88——3
(11) $am3ts\gamma \times op6$	# 5	43	ts	γ6-3
(12) $am3ts_{\gamma} \times am27$	#	95	wt	γ3-27
(13) $am3ts9 \times am27$	3	37	ts	3-279
_	2.3 ± 0.4	16	am	31169
_	₹	39	am	116—9-33
$(16) \ am33ts116 \times am50$	#	68	wt	
(17) am33ts116 \times am86		77	wt	11633-86
(18) $am331s4 \times am16$	#	95	W	4
(19) am331s79 \times ts γ	$\overline{}$	79	W	3379
(20) $am33ts\gamma \times amN1$	-	34	ts	
(21) $am9ts128 \times amN1$	#	7	ts	128NI9
(22) $am331s\gamma \times am86$	$\overline{}$	43	ts	33-86γ
(23) $am9ts128 \times am88$		8	wt	128988
$(24) \ am881s79 \times och6$	10.8 + 2.3	93	J.M.	9
	1.4 + 0.3	95	J.M.	γ6
(26) am3ts9 \times och6	1.0 + 0.4	45	ts.	369
_	Low burst	4	am	
_	Low burst	9	am	311
_	Low burst	95	wt	361
(30) am3och6 \times och5	Low burst	86	wt	365
(31) am331s116 \times och6	3.9 ± 0.4	21	ts	611633
(32) am $33ts4 \times och6$	41	26	wt	64

(33) $am88ts79 \times am10$		8	W	798810
(34) $am3ts79 \times am10$	1.4 ± 0.7	8	W	79310
(35) am3 $ts_{\gamma} \times am10$		8	wt	γ ———3———10
(36) $am3ts9 \times am10$	1.6 ± 0.1	45	ts	39
(37) am33ts116 × am35 (38) am33ts116 × am18	18.4 ± 1.2 21.9 ± 6.8	55 56	Intermediate Intermediate	116 - (35, 33) $116 - (18, 33)$

* Values expressed \times 104. This cross demonstrates that 1s79 segregants are not outgrown by wt segregants in crosses 4, 5, 7, and 33.

type. [This distortion was also seen by Baker and Tessman (1).]

The genotype which is not predominant is always present in at least 5% of the recombinant progeny. This high negative interference is shown in Table 4 by selecting single $am \times am$ recombinant plaques at 30 C and testing for segregation of ts marker by plating at both 30 and 40 C. Four-factor crosses of the type am- $ts \times am$ -cs, selecting for recombination between the am markers, confirm this by showing that all four of the recombinant genotypes thus selected, +++++, +++cs, ts+++, and ts++cs, are generated in significant amounts.

The placement of cistron C is more difficult since only a single *och* mutant site has been isolated, i.e., three independent *och* isolates complementing in cistron C show no recombination (5×10^{-6}) among themselves. The two-factor data in Table 2 are ambiguous; *och*6 generally exhibits low recombination frequencies. Three-factor crosses in Table 3 appear to place *och*6 unequivocally. However, the crucial crosses, 27, 28, 29, and 30, are of the type *och am* \times *och* for which we have no suitable controls (i.e., crosses with *och* mutants in cistrons of known location). With this reservation, cistron C has a clearly defined map position between cistron B and cistron E.

Cistron D is also placed between cistrons B and E by the three-factor crosses in Table 3. Unfortunately, reciprocal crosses of the type $am \ ts \times ts$ or $am \ ts \times am$ cannot be carried out because our nonsense mutants in cistron D are temperature-sensitive when grown in our suppressor-carrying hosts. The placement of cistron D relative to cistron C depends on the fact that the cross $am33ts116 \times am10$ segregates a lower percentage (25%) of ts recombinants on a nonpermissive strain than does the cross $am33ts116 \times ach6$ (79%). This strongly indicates that ach6 and

ts116 are very closely linked, whereas am10 and ts116 are more widely separated markers.

We would like to note that the location of the cistron A mutants, am18 and am35, relative to am33 is uncertain (Table 3; see below for discussion). With these two exceptions, the three-factor cross data in Table 3 provide our strongest self-consistent evidence for the ordering of the eight known cistrons of $\phi X174$.

DISCUSSION

Two-factor recombination frequencies provide a consistent marker order in many cases. Exceptions generally involve two or three closely linked markers widely separated from neighboring markers, i.e., the set am10, am3, and am6 or the pair am14 and am16, for example.

The low recombination frequencies found with most cistron E mutants in certain crosses arise because single bursts in these crosses are exceptionally large and asymmetric even under permissive growth conditions. An allelic ratio of 4:1 or more in favor of the cistron E mutant is obtained (Benbow, Davis, and Sinsheimer, in preparation). The low recombination frequency is thus an artifact of our method of calculating the recombination frequency by dividing the wt progeny by the total progeny since cistron E mutants can rapidly outgrow many partially supressed am mutants.

In contrast to the widespread occurrence of am and op (unpublished data) nonsense mutations, och mutants have been located in only two cistrons (B and C). It is of interest that these och mutations (the presumed in vivo termination codons) are found only in the last two cistrons to undergo translation (Benbow et al., in preparation).

The high recombination region found within cistron A was observed by Hutchison (Ph.D. Thesis) and also by Tessman (18) in cistron IV of bacteriophage S13. (See Table 5 for an com-

Table 4. Illustration of high negative interference

				Per c	ent wt
Type of cross	Cross	ts	wt	Single colonies	Mass plating
Three factor	am9ts128 × amN1 am88ts79 × am9 am88ts79 × am3	107 65 14	5 35 116	4.5 35 92	7 38 91
		cs++ts	+++ts	cs+++	++++
Four factor	am3cs70 × am88ts79 am3cs70 × amN1ts.	23 41	19 42	136 132	43 12

TABLE 5.	Cistrons of bacteriophages
	$\phi X174$ and $S13^a$

New	Pre	vious designat	ions
designation	φX174 (Sinsheimer)	φX174 (Hayashi)	S13 (Tessman)
Α	VI	С	IV
В	IV	В	II
C	VIII	H (?)	VI (?)
D	V	D`	VII
Е	I	G	V
F	VII	Е	I
G	III	F	IIIa
Н	II	Α	IIIb
I		I	

^a Above nomenclature and correspondence of cistrons were agreed upon at the small deoxyribonucleic acid phage conference held at the California Institute of Technology on 7 November 1970.

parison of $\phi X174$ and S13 cistrons from various laboratories.) It may arise because one strand frequently is nicked in this region during replication. Alternatively, these mutants may remain longer on the membrane or be exposed to some other physiological circumstance such as an altered deoxyribonucleic acid configuration that stimulates recombination. In this context, we would like to note that, although we have drawn our map as circular in Fig. 1, the data in Table 2 can be represented as shown in Fig. 2, after making the assumption that exchanges within cistron A usually are paired. The physical significance of this is unknown at present.

The order of $\phi X174$ cistrons agrees with the order of Baker and Tessman (1) of six homologous S13 genes [using the homologies determined by the complementation tests of Hutchison (Ph.D. Thesis)]. S13 cistron VI, which previously was mapped between our $\phi X174$ cistrons E and F (1), now corresponds to our position for cistron C (I. Tessman, personal communication). The existence of a ninth complementation group has also been reported (M. Hayashi, personal communication). The general features of the $\phi X174$ genetic map, its additivity, circularity, and high negative interference, are similar to those previously established for the related bacteriophage S13 (1, 18).

The occurrence of high negative interference (1, 9) is indicated by our three-factor genetic cross data. Even for a closely linked outside marker, both external genotypes are found in significant percentages after a recombination event. This is confirmed by the four-factor crosses in Table 4 in which all four possible genotypes

are found in significant amounts after selection for recombination between two markers. This makes sense if genetic recombination of $\phi X174$ involves hybrid regions of 500 or more nucleotides on either side of a duplex breakage and reunion region (13). Since there are only 5,500 nucleotides in the entire $\phi X174$ genome, gene conversion by deoxyribonucleic acid repair should occur over a significant portion of the genetic map resulting in the high negative interference observed.

The sum of the shortest distances between two mutations often adds up to more than the measured value, although the order of the markers is usually unambiguous. This "map contraction" may be related to the phenomenon of "map expansion" shown by Holliday (10). Alternatively,

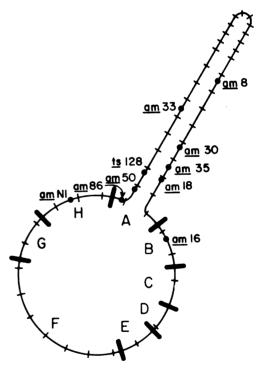


Fig. 2. Frequency of wt recombinants in two-factor genetic crosses between $\phi X174$ conditional lethal nonsense mutants taken from Table 2. This map is identical to Fig. 1, except that the cistron A region has been drawn to scale to illustrate the very high recombination frequencies found for certain cistron A mutants. To do this, the critical assumption made is that cistrons H and B are closely linked, i.e., that recombination events within the cistron A "loop" usually occur in pairs so that the cistron A region is inert genetically with respect to the rest of the genome. The similarity between this diagram and the previously suggested structure for an exonuclease I-resistant deoxyribonucleic acid fragment of $\phi X174$ (6) is striking.

it may result from the physical constraints of a small circular genome. We do not know the effect, if any, this has on three-factor crosses.

In concluding we would like to point out that bacteriophage $\phi X174$ provides a unique opportunity for genetic analysis in that a fine structure map (2) of the entire genome may be constructed. Unlike the case for most other viruses, single-burst experiments measuring production both of recombinants and of total progeny phage provide the equivalent of single tetrad analysis in fungi (10) since recombination events are very infrequent. Furthermore, most, if not all, of the cistron products of $\phi X174$ are well characterized (8, 3, 12), and, therefore, physical verification of the genetic analysis is easily obtained.

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